### LITEON SEMICONDUCTOR

#### SURFACE MOUNT ULTRA FAST RECTIFIER

## US1A thru US1M

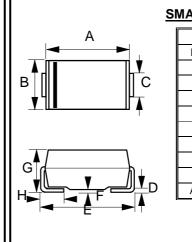
REVERSE VOLTAGE - 50 to 1000 Volts FORWARD CURRENT - 1.0 Amperes

#### FEATURES

- Glass passivated chip
- Ultra fast switching for high efficiency
- Low forward voltage drop and high current capability
- Low reverse leakage current

#### **MECHANICAL DATA**

- Case : Molded plastic
- Case Material: "Green" Molding compound, UL flammability classification 94V- 0, (No Br. Sb. Cl.) "Halogen-free"
- Polarity : Indicated by cathode band
- Weight: 0.002 ounces , 0.069 grams (Approximate)



<u>IA</u>							
<u>SMA</u>							
DIM	MIN	MAX					
А	4.06	4.57					
В	2.29	2.92					
С	1.27	1.63					
D	0.15	0.31					
Е	4.83	5.59					
F	0.05	0.20					
G	2.01	2.40					
Н	0.76	1.52					
All Dimensions in millimeter							

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25℃ ambient temperature unless otherwis e specified.

#### **ABSOLUTE RATINGS**

	<u> </u>							-			-
PARA	METER		SYMBOL	US1A	US1B	US1D	US1G	US1J	US1K	US1M	UNIT
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	50	100	200	400	600	800	1000	V	
Maximum RMS voltage			V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC Blocking volta	age		V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Maximum Average rectified current	forward	@T∟=110 ℃	I <sub>F</sub>	1.0				A			
Peak forward surge single h sine-wave	nalf	@tp=8.3ms	I <sub>FSM</sub>	30				А			
Operating ant Storage temp	perature rang	ge	T <sub>J,</sub> T <sub>STG</sub>				-55 ~ +150	C			C
STATIC ELECTRICAL	L CHARA	CTERISTICS									
PARAMETER	TEST	CONDITION	SYMBOL				MAX				UNIT
Forward voltage (Note 1)	I <sub>F</sub> =1A	T <sub>J</sub> = 25℃	V <sub>F</sub>		1.0		1.3		1.7		V
Reverse leakage current at blocking voltage	Rated DC	T <sub>J</sub> = 25℃ T <sub>J</sub> = 100℃	I <sub>R</sub>				5.0 50				uA
Typical junction capacitance	e(Note 2)		Cj		20 10			pF			
THERMAL CHARAC	TERISTIC	S									
PARA	METER		SYMBOL				TYP				UNIT
			RthJ <sub>A</sub>				60				
Typical thermal resistance(Note 3)		RthJ∟	22					°C/W			
		RthJ <sub>c</sub>	18								
DYNAMIC ELECTRIC	CAL CHA	RACTERISTI	ĊS								
PARAMETER		SYMBOL	MAX				UNIT				
Peverse recovery time		-0.254 L -1.04	т			50		1	75		nS

Reverse recovery time $I_F=0.5A, I_{rr}=0.25A, I_{R}=1.0A$ $T_{rr}$ 50 75 nS	Note :				REV. 10, Jun-2015, KS	FA01
	Reverse recovery time	I <sub>F</sub> =0.5A,I <sub>rr</sub> =0.25A,I <sub>R</sub> =1.0A	Trr	50	(5	nS

(1) 300us pulse with, 2% duty cycle

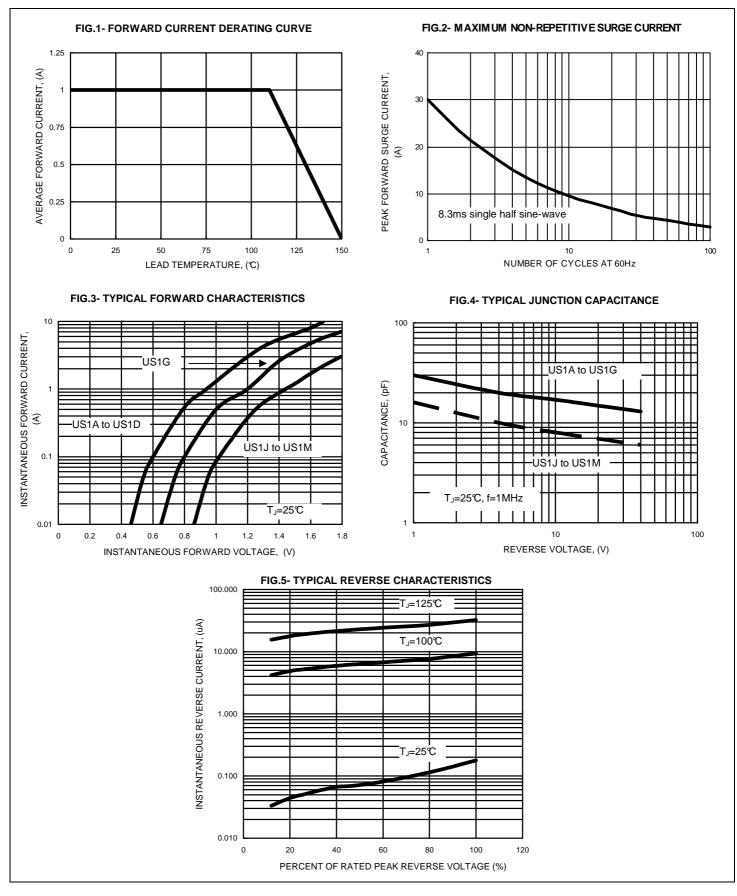
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(2) Measured at 1.0MHz and reverse voltage of 4.0V DC.

(3) Thermal resistance junction to Ambient, Lead and Case

# RATING AND CHARACTERISTIC CURVES US1A thru US1M

# LITEON



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